

To our customers,

Old Company Name in Catalogs and Other Documents

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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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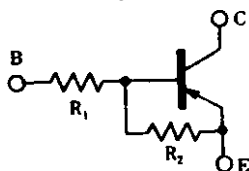


COMPOUND TRANSISTOR FP1 SERIES

on-chip resistor PNP silicon epitaxial transistor
For mid-speed switching

FEATURES

- Up to 0.7 A current drive available
- On-chip bias resistor
- Low power consumption during drive



QUALITY GRADES

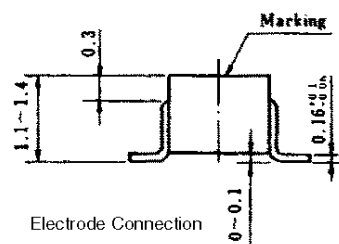
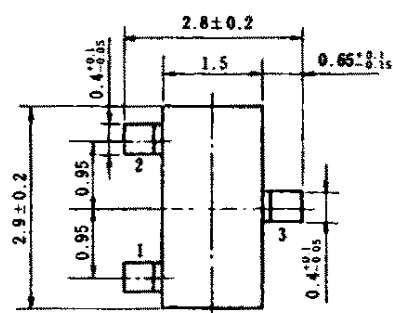
- Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

FP1 SERIES LISTS

Products	Marking	R ₁ (KΩ)	R ₂ (KΩ)
FP1A4A	S30	—	10
FP1L2Q	S31	0.47	4.7
FP1A3M	S32	1.0	1.0
FP1F3P	S33	2.2	10
FP1J3P	S36	3.3	10
FP1L3N	S34	4.7	10
FP1A4M	S35	10	10

PACKAGE DRAWING (UNIT: mm)



Electrode Connection

1. Emitter (E)
2. Base (B)
3. Collector (C)

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CB0}	-25	V
Collector to emitter voltage	V _{CE0}	-25	V
Emitter to base voltage	V _{EB0}	-10	V
Collector current (DC)	I _{C(DC)}	-0.7	A
Collector current (Pulse)	I _{C(pulse)} *	-1.0	A
Base current (DC)	I _{B(DC)}	-20	mA
Total power dissipation	P _T	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

* PW ≤ 10 ms, duty cycle ≤ 50 %

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FP1A4A

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	I _{CBO}	V _{CB} = -22 V, I _E = 0			-100	nA
DC current gain	h _{FE1} **	V _{CE} = -2.0 V, I _C = -0.1 A	200			-
DC current gain	h _{FE2} **	V _{CE} = -2.0 V, I _C = -0.5 A	100			-
DC current gain	h _{FE3} **	V _{CE} = -2.0 V, I _C = -0.7 A	50			-
Collector saturation voltage	V _{CE(sat)} **	I _C = -0.3 A, I _B = -6 mA		0.28	0.4	V
Low level input voltage	V _{IL} **	V _{CE} = -5.0 V, I _C = -100 μA			-0.3	V
Input resistance	R ₁		-	-	-	Ω
E-to-B resistance	R ₂		7	10	13	kΩ

** PW ≤ 350 μs, duty cycle ≤ 2 %

FP1L2Q

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	I _{CBO}	V _{CB} = -22 V, I _E = 0			-100	nA
DC current gain	h _{FE1} **	V _{CE} = -2.0 V, I _C = -0.1 A	150	350		-
DC current gain	h _{FE2} **	V _{CE} = -2.0 V, I _C = -0.5 A	100	300		-
DC current gain	h _{FE3} **	V _{CE} = -2.0 V, I _C = -0.7 A	50	200		-
Low level output voltage	V _{OL} **	V _{IN} = -5.0 V, I _C = -0.3 A		-0.3	-0.4	V
Low level input voltage	V _{IL} **	V _{CE} = -5.0 V, I _C = -100 μA		-0.65	-0.3	V
Input resistance	R ₁		329	470	611	Ω
E-to-B resistance	R ₂		3.29	4.7	6.11	kΩ

** PW ≤ 350 μs, duty cycle ≤ 2 %

FP1A3M

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	I _{CBO}	V _{CB} = -22 V, I _E = 0			100	nA
DC current gain	h _{FE1} **	V _{CE} = -2.0 V, I _C = -0.1 A	80			-
DC current gain	h _{FE2} **	V _{CE} = -2.0 V, I _C = -0.5 A	100			-
DC current gain	h _{FE3} **	V _{CE} = -2.0 V, I _C = -0.7 A	50			-
Low level output voltage	V _{OL} **	V _{IN} = -5.0 V, I _C = -0.2 A		-0.3	-0.4	V
Low level input voltage	V _{IL} **	V _{CE} = -5.0 V, I _C = -100 μA			-0.3	V
Input resistance	R ₁		0.7	1.0	1.3	kΩ
E-to-B resistance	R ₂		0.7	1.0	1.3	kΩ

** PW ≤ 350 μs, duty cycle ≤ 2 %

FP1F3P
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	ICBO	V _{CB} = -22 V, I _E = 0			-100	nA
DC current gain	h _{FE1} **	V _{CE} = -2.0 V, I _C = -0.1 A	200			-
DC current gain	h _{FE2} **	V _{CE} = -2.0 V, I _C = -0.5 A	100			-
DC current gain	h _{FE3} **	V _{CE} = -2.0 V, I _C = -0.7 A	50			-
Low level output voltage	V _{OL} **	V _{IN} = -5.0 V, I _C = -0.2 A			-0.4	V
Low level input voltage	V _{IL} **	V _{CE} = -5.0 V, I _C = -100 μA			-0.3	V
Input resistance	R ₁		1.54	2.2	2.86	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

** PW ≤ 350 μs, duty cycle ≤ 2 %

FP1J3P
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	ICBO	V _{CB} = -22 V, I _E = 0			-100	nA
DC current gain	h _{FE1} **	V _{CE} = -2.0 V, I _C = -0.1 A	200	470		-
DC current gain	h _{FE2} **	V _{CE} = -2.0 V, I _C = -0.5 A	100	300		-
DC current gain	h _{FE3} **	V _{CE} = -2.0 V, I _C = -0.7 A	50	200		-
Low level output voltage	V _{OL} **	V _{IN} = -5.0 V, I _C = -150 mA		-0.2	-0.4	V
Low level input voltage	V _{IL} **	V _{CE} = -5.0 V, I _C = -100 μA		-0.65	-0.3	V
Input resistance	R ₁		2.3	3.3	4.3	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

** PW ≤ 350 μs, duty cycle ≤ 2 %

FP1L3N
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	ICBO	V _{CB} = -22 V, I _E = 0			-100	nA
DC current gain	h _{FE1} **	V _{CE} = -2.0 V, I _C = -0.1 A	200			-
DC current gain	h _{FE2} **	V _{CE} = -2.0 V, I _C = -0.5 A	100			-
DC current gain	h _{FE3} **	V _{CE} = -2.0 V, I _C = -0.7 A	50			-
Low level output voltage	V _{OL} **	V _{IN} = -5.0 V, I _C = -150 mA			-0.45	V
Low level input voltage	V _{IL} **	V _{CE} = -5.0 V, I _C = -100 μA			-0.3	V
Input resistance	R ₁		3.29	4.7	6.11	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

** PW ≤ 350 μs, duty cycle ≤ 2 %

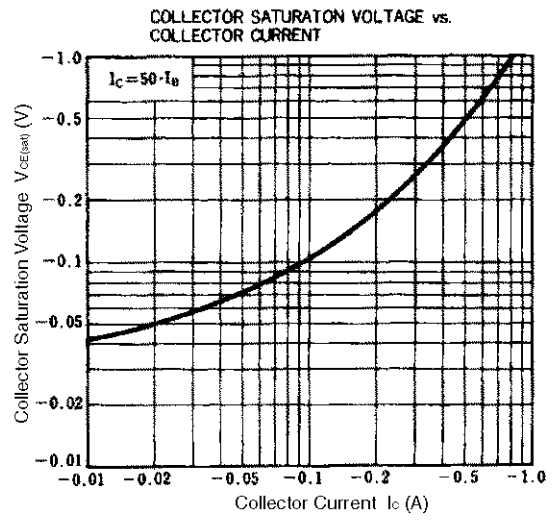
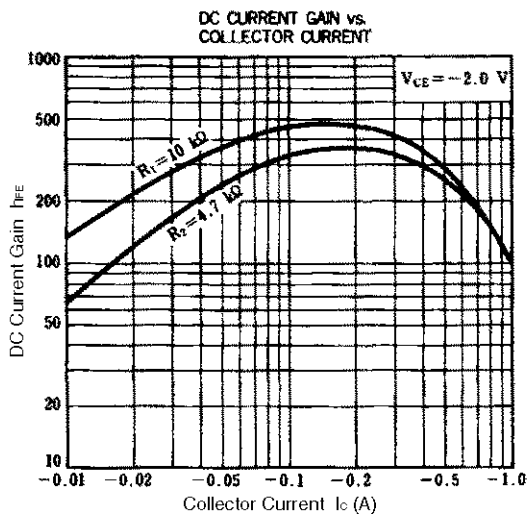
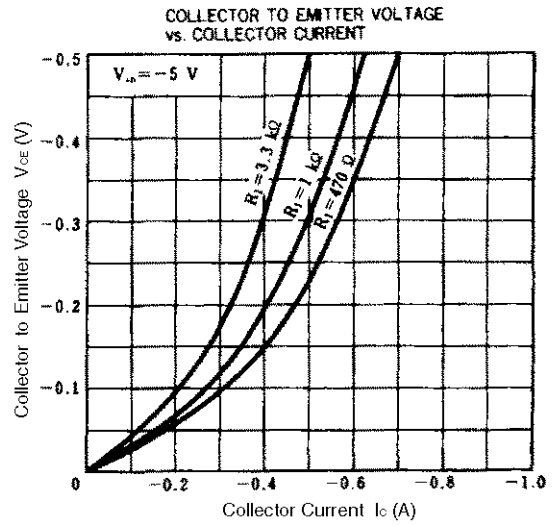
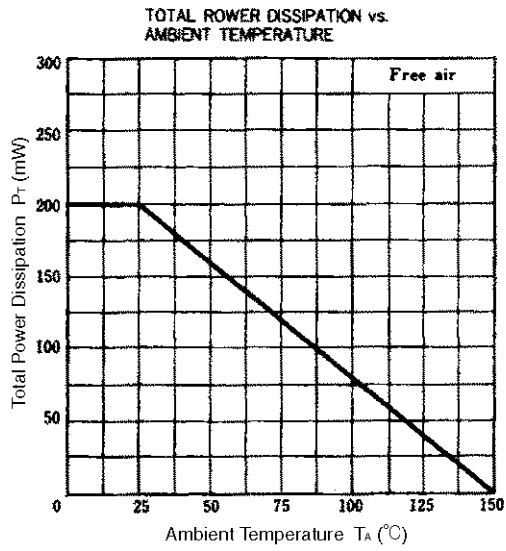
FB1A4M

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	I _{CB0}	V _{CB} = -22 V, I _E = 0			-100	nA
DC current gain	h _{FE1} **	V _{CE} = -2.0 V, I _C = -0.1 A	200			-
DC current gain	h _{FE2} **	V _{CE} = -2.0 V, I _C = -0.5 A	100			-
DC current gain	h _{FE3} **	V _{CE} = -2.0 V, I _C = -0.7 A	50			-
Collector saturation voltage	V _{CE(sat)} **	V _{IN} = -5.0 V, I _C = -0.1 A			-0.4	V
Low level input voltage	V _{IL} **	V _{CE} = -5.0 V, I _C = -100 μA			-0.3	V
Input resistance	R ₁		7	10	13	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

** PW ≤ 350 μs, duty cycle ≤ 2 %

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, contact an NEC sales representative.

Surface MOUNTING TYPE

For details of the recommended soldering conditions, refer to the document Semiconductor Device Mounting Technology Manual (C10535E).

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 230°C, Time: 30 sec. max. (at 210°C or higher), Count: Once, Exposure limit: None *	IR30-00
VPS	Package peak temperature: 215°C, Time: 40 sec. max. (at 200°C or higher), Count: Once, Exposure limit: None *	VP15-00
Partial heating	Pin temperature: 300°C max., Time: 10 sec. max. Exposure limit: None *	O

* After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

Cautions 1. Do not use different soldering methods together (except for partial heating).

- 2. Prevent the resin surface temperature from being higher than the board temperature by 20°C or more.**

[MEMO]

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